



## **IEEE Egypt Section Solid-State Circuits Society (SSCS) Chapter 2024 Student Design**

The IEEE Egypt Section SSCS Chapter is holding a student design competition in the summer of 2024. This contest asks students to design a low-dropout regulator (LDO) with the specs given below. The operation of the circuit should be demonstrated by a report that includes the simulation results of all the specs and the transient response  $FOM_T$ . Monetary awards will be provided for the top three designs. The registration deadline is July 25, 2023. Please, register your team (1-4 students) by filling in [this form](#) before the deadline.

### **Eligibility Criteria**

The competition is particularly intended for undergraduate students from public, private, or national universities within Egypt. Students graduating this year aren't qualified to enter the competition.

### **2024 Competition Technical Details**

This competition aims to design and simulate a low-drop regulator (LDO) with the specifications given in Table 1 with the highest FOM. The LDO designs will be compared based on the FOM given that all the specifications are met.

Table 1. Required LDO Specifications

Parameter	Name	Min	Typ	Max	Units	Comments
Power Supply Voltage	$V_{in}$	2.4		3.5	V	
Output Voltage	$V_{out}$	0.85	1	1.25	V	Programmable with 12.5 mV step
Untrimmed Output Voltage Accuracy			$\pm 6$		%	
Load Current	$I_{out}$	0.1		150	mA	
Vin Ramp Rate	$dV_{in}/dt$			0.2	mV/ $\mu$ s	
Rate of Iout Change	$dI_{out}/dt$			5	mA/ns	Load transient regulation for maximum load variation at maximum capacitance
Undershoot/Overshoot				50	mV/ $\mu$ s	
Load Capacitance	$C_L$			1	nF	
Power Supply Rejection at 1 MHz	$PSR_{1MHz}$	30			dB	
Power Supply Rejection at 10 MHz	$PSR_{10MHz}$	20			dB	
Line Regulation			2		mV/V	
Load Regulation			50		mV/A	

## Instructions

1. Use a single supply DC voltage source.
2. Make sure that the phase margin is  $> 45^\circ$  for all the negative feedback loops in your design.
3. Load transient profile from 1mA to 150mA within 30nsec and from 150mA to 1mA within 30nsec.
4. Transient response  $FOM_T = \frac{C_L * \Delta V_{out} * I_q}{I_{L,max}^2}$
5. Assume any missing information.

## Deliverables

You should submit a report that includes the simulation results of all the specifications in Table 1 in addition to the quiescent current and the  $FOM_T$ . The table should look like Table 2.

Table 2. Required Table Format

Parameter	Name	Specifications			Simulation Results			Units
		Min	Typ	Max	Min	Typ	Max	
Power Supply Voltage	$V_{in}$	2.4		3.5				V
Output Voltage	$V_{out}$	0.85	1	1.25				V
Untrimmed Output Voltage Accuracy			$\pm 6$					%
Load Current	$I_{out}$	0.1		150				mA
Vin Ramp Rate	$dV_{in}/dt$			0.2				mV/ $\mu$ s
Rate of Iout Change	$dI_{out}/dt$			5				mA/ns
Undershoot/Overshoot				50				mV/ $\mu$ s



Load Capacitance	$C_L$			1				nF
Power Supply Rejection at 1 MHz	$PSR_{1MHz}$	30						dB
Power Supply Rejection at 10 MHz	$PSR_{10MHz}$	20						dB
Line Regulation			2					mV/V
Load Regulation			50					mV/A
Quiescent Current	$I_q$							$\mu A$
$FOM_T$								nSec

## Timeline for submission

Students should submit a report summarizing their designs by September 15, 2024. The winners will be announced by September 30, 2024.

## Awards

Gold Award: \$350

Silver Award: \$250

Bronze Award: \$150